TECHNICAL DATA
DATA SHEET 4637, REV.-

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 45 VOLT, 45 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC LCC-3P PACKAGE.

MAXIMUM RATINGS ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

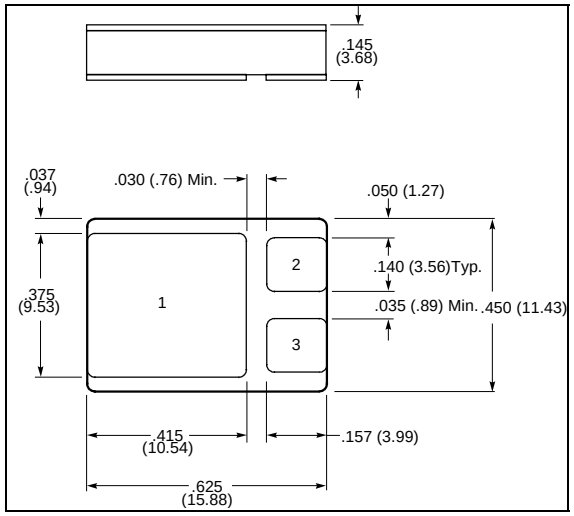
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	45	Volts
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_C=100 ^{O}C) (Single)	I_O	45	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I_{FSM}	200	Amps
MAXIMUM JUNCTION CAPACITANCE (V_r=5V)	C_T	4800	pF
MAXIMUM THERMAL RESISTANCE	$R_{\theta JC}$	0.25	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 150	°C

ELECTRICAL CHARACTERISTICS

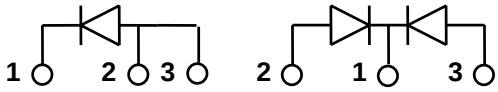
CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I_f = 45 Amps)			
T_J = 25 °C	V_f	0.60	Volts
T_J = 125°C		0.50	
MAXIMUM REVERSE CURRENT (I_r @ 45 V PIV)			
T_J = 25 °C	I_r	9	mA
T_J = 125 °C		420	

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DATA SHEET 4637, REV. -

MECHANICAL DIMENSIONS: IN Inches / mm



SINGLE **COMMON CATHODE**

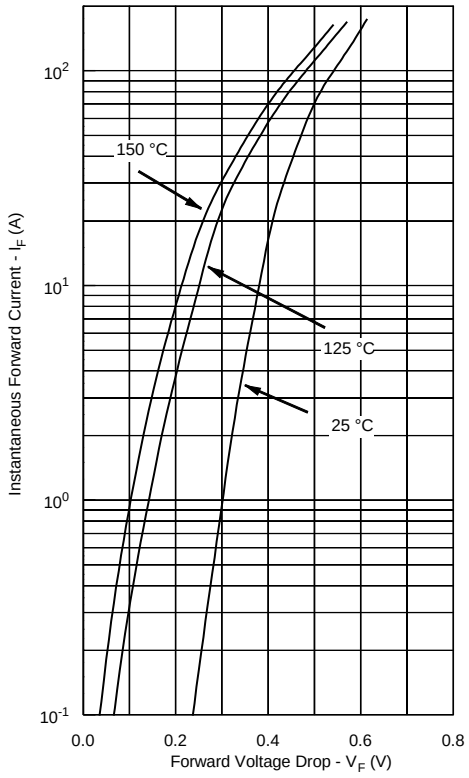


LCC-3P

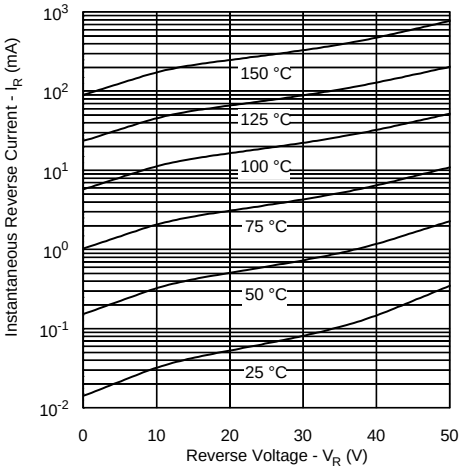
PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE	COMMON CATHODE	ANODE 1	ANODE 2

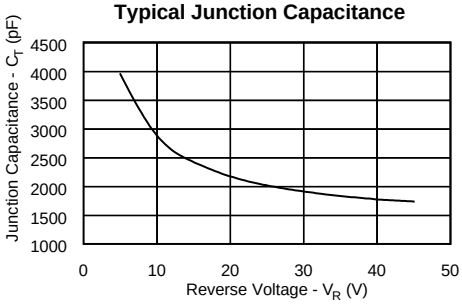
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



TECHNICAL DATA

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